NSN 5961-00-233-9887

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-233-9887 **Inclosure Material:** Glass **Overall Length:** 0.450 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, peak **Current Rating Per Characteristic:** 20.00 amperes forward current, average absolute and 50.00 microamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0